



#### 100V N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>C</sub> = +25°C
	22mΩ @ V <sub>GS</sub> = 10V	47.2A
100V	30mΩ @ V <sub>GS</sub> = 6.0V	40.4A
	43.7mΩ @ V <sub>GS</sub> = 4.5V	33.5A

### **Description**

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

### **Applications**

- Power Management Functions
- DC-DC Converters
- Backlighting

### **Features**

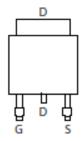
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub> Minimizes Power Losses
- Low Q<sub>G</sub> Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

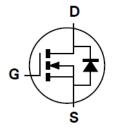
- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.33 grams (Approximate)







Pin Out Top View



Equivalent Circuit

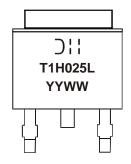
### Ordering Information (Note 4)

Part Number	Case	Packaging
DMT10H025LK3-13	TO252 (DPAK)	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## **Marking Information**



Oll = Manufacturer's Marking
T1H025L = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 18 = 2018)
WW = Week Code (01 to 53)



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit		
Drain-Source Voltage		V <sub>DSS</sub>	100	V		
Gate-Source Voltage		V <sub>GSS</sub>	±20	V		
Continuous Prais Current // 10//	T <sub>C</sub> = +25°C	I <sub>D</sub>	47.2	А		
Continuous Drain Current, V <sub>GS</sub> = 10V	$T_C = +70$ °C		37.7			
Pulsed Drain Current (10µs Pulse, T <sub>C</sub> = +25°C, Package Limited)		I <sub>DM</sub>	185	А		
Pulsed Body Diode Forward Current (10µs Pulse, T <sub>C</sub> = +25°C, Package Limited)		I <sub>SM</sub>	185	A		
Maximum Continuous Body Diode Forward Current (Note 6)		ximum Continuous Body Diode Forward Current (Note 6)		I <sub>S</sub>	2.6	A
Avalanche Current, L = 0.1mH		I <sub>AS</sub>	15.8	A		
Avalanche Energy, L = 0.1mH		E <sub>AS</sub>	12.5	mJ		

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P <sub>D</sub>	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	48	°C/W
Total Power Dissipation (Note 6)	P <sub>D</sub>	83	W	
Thermal Resistance, Junction to Case (Note 6)		R <sub>0JC</sub>	1.5	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

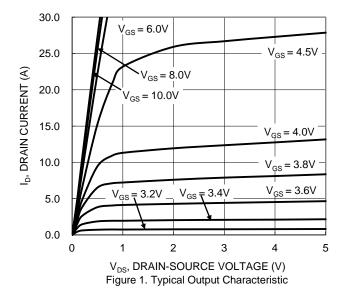
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	_	_	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>			1	$\mu A$ $V_{DS} = 80V, V_{GS} = 0V$		
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1		3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
		_	17.1	22		$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	21.4	30	mΩ	$V_{GS} = 6V, I_D = 20A$	
	, .	_	28.3	43.7		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 20A	
Diode Forward Voltage	$V_{SD}$	_	_	1.3	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	1477	_		V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V f = 1MHz	
Output Capacitance	Coss	_	263		pF		
Reverse Transfer Capacitance	Crss	_	20	_		I = IIVIHZ	
Gate Resistance	$R_{G}$	_	1.3	_	$\Omega$ $V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$		
Total Gate Charge	Q <sub>G</sub>	_	21	_		5044 504	
Gate-Source Charge	Q <sub>GS</sub>	1	5.7	1	nC	$V_{DD} = 50V, I_D = 20A,$	
Gate-Drain Charge	Q <sub>GD</sub>	_	3.8	_		$V_{GS} = 10V$	
Turn-On Delay Time	t <sub>D(ON)</sub>		6.3			$V_{DD} = 50V, V_{GS} = 10V,$ $I_{D} = 20A, R_{G} = 6\Omega$	
Turn-On Rise Time	t <sub>R</sub>		9.4				
Turn-Off Delay Time	t <sub>D(OFF)</sub>		16.7		ns		
Turn-Off Fall Time	t <sub>F</sub>		8.2				
Reverse Recovery Time	t <sub>RR</sub>		38.7		ns		
Reverse Recovery Charge	Q <sub>RR</sub>		53.7		$_{\rm nC}$ I <sub>F</sub> = 20A, di/dt = 100A/µs		

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.

8. Guaranteed by design. Not subject to product testing.

<sup>7.</sup> Short duration pulse test used to minimize self-heating effect.





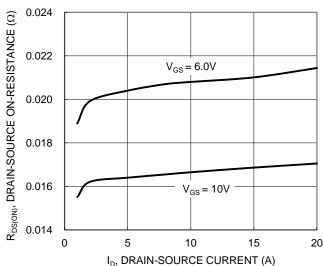


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

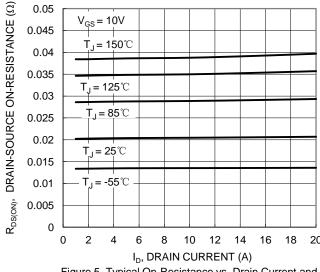


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

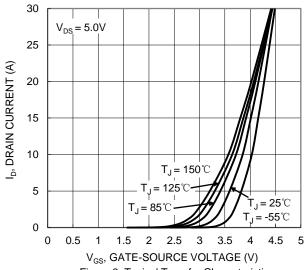


Figure 2. Typical Transfer Characteristic

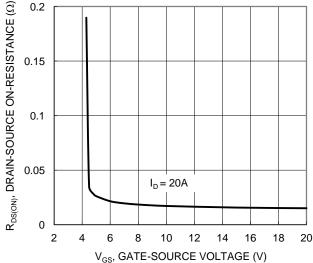


Figure 4. Typical Transfer Characteristic

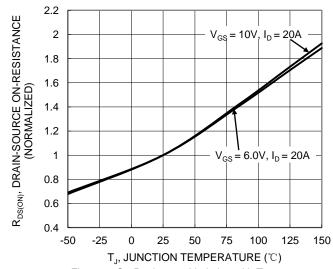


Figure 6. On-Resistance Variation with Temperature



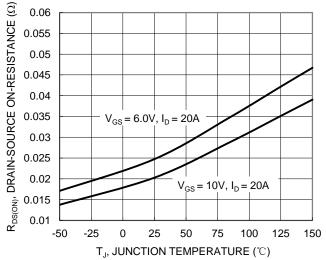


Figure 7. On-Resistance Variation with Temperature

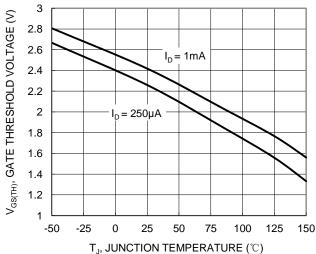


Figure 8. Gate Threshold Variation vs. Junction
Temperature

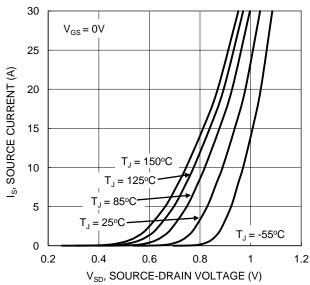
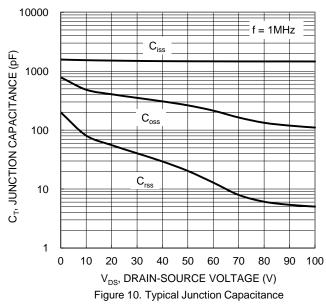
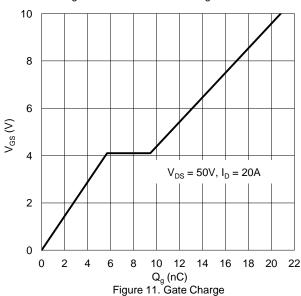
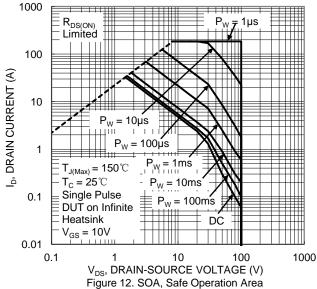


Figure 9. Diode Forward Voltage vs. Current









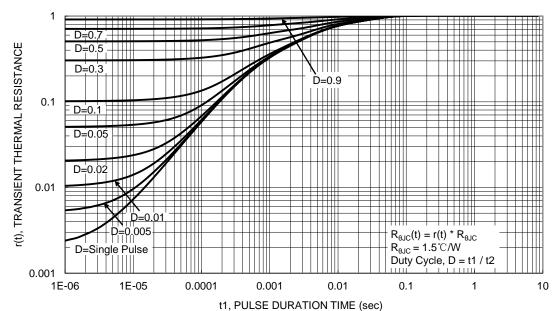


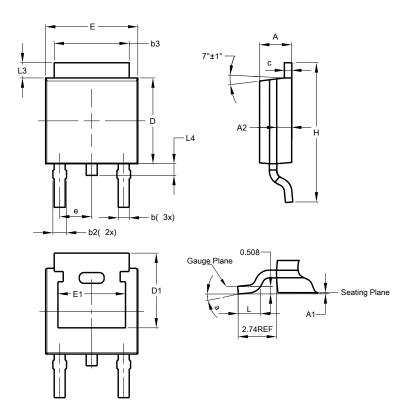
Figure 13. Transient Thermal Resistance



### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### TO252 (DPAK)

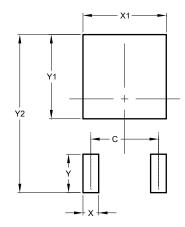


TO252 (DPAK)				
Dim	Min	Max		
			Тур	
Α	2.19	2.39	2.29	
<b>A</b> 1	0.00	0.13	0.08	
A2	0.97	1.17	1.07	
b	0.64	0.88	0.783	
b2	0.76	1.14	0.95	
b3	5.21	5.46	5.33	
С	0.45	0.58	0.531	
D	6.00	6.20	6.10	
D1	5.21	-	-	
е	-	-	2.286	
Е	6.45	6.70	6.58	
E1	4.32	-	-	
Н	9.40	10.41	9.91	
L	1.40	1.78	1.59	
L3	0.88	1.27	1.08	
L4	0.64	1.02	0.83	
а	0°	10°	-	
All Dimensions in mm				

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### TO252 (DPAK)



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Υ	2.600		
Y1	5.700		
V2	10 700		



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